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TRANSMITTAL LETTER (General - Patent Pending)				Docket No. FIS920030190 (00750482AA)	
In Re Astrication Belyansky et al.					
Application No. 10/695,752	Filing Date 10/30/2003	Examiner E. Wojciechowicz	Customer No. 30743	Group Art Unit 2815	Confirmation No. 6187
Title: STRUCTUI		O IMPROVE CHANNEL	MOBILITY BY GA	TE ELECTROI	DE STRESS
COMMISSIONER FOR PATENTS:					
Response to Requ Postcard	irement for Restrictio	n			
in the above identi	fied application.				
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Mars	Signature	Put,	Dated: Aug	gust 30, 2004	
Marshall M. Curtis Reg. No. 33,138					
	Christofferson, P.C. Road, Suite 340		deposited with sufficient postal addressed to the 1450, Alexandri	th the United State age as first class the "Commissioner ia, VA 22313-1450"	(Date)
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N THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Michael P. Belyansky et al. Conf. No.: 6187

Serial No.: 10/695,752 Group Art Unit: 2815

Filed: October 30, 2003 Examiner: E. Wojciechowicz

For: STRUCTURE AND METHOD TO IMPROVE CHANNEL MOBILITY

BY GATE ELECTRODE STRESS MODIFICATION

Commissioner for Patents United States Patent and Trademark Office P. O. Box 1450 Alexandria, Virginia 22313-1450

RESPONSE TO REQUIREMENT FOR RESTRICTION

Sir:

In response to the Office Action mailed July 28, 2004, Applicants provisionally elect, without traverse, the invention as defined by the claims of Group II, claims 1 - 12, as identified by the Examiner, for further prosecution on their merits.

REMARKS

Claims 1 - 20 remain active in this application. No new matter has been introduced into the application.

Restriction has been required between the inventions, as identified by the Examiner, of Group I, claims 13 - 20, directed to a semiconductor device, and Group II, claims 1 - 12, directed to a method of making a semiconductor device. Provisional election of the invention of Group II, claims 1 - 12, has been made without traverse, above.